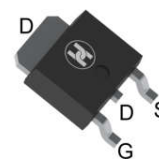


N-CHANNEL Power MOSFET

FEATURES

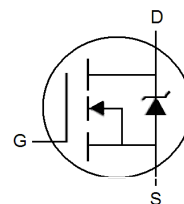
- V_{DS} : 60V , I_D :80A Max
- $R_{DS(ON)}$:8 m Ω (max.)@ $V_{GS}=10V$, $I_D=20A$
- High density cell design for ultra low on-resistance
- Fully characterized avalanche voltage and current



TO-252

MECHANICAL DATA

- Case: TO-252
- Case material: Molded Plastic. UL flammability 94V-0
- Weight:0.33grams(approximate)
- Marking:D80N06



EQUIVALENT CIRCUIT

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	60	V
Gate-source voltage	V_{GS}	± 20	V
Continuous drain current	I_D	80	A
Pulsed drain current (Note 1)	I_{DM}	240	A
Power dissipation	P_D	100	W
Thermal resistance from junction to ambient	$R_{\theta JC}$	5.5	$^\circ\text{C/W}$
Thermal Resistance,Junction-to-Case	T_J, T_{STG}	-55~+150	$^\circ\text{C}$
Single Pulsed Avalanche Energy (note 1)	E_{AS}	180	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10s)	T_L	260	$^\circ\text{C}$

Note: 1. E_{AS} condition: $V_{DD}=20V$, $L=0.5mH$, $R_G=25\Omega$, Starting $T_J = 25^\circ\text{C}$

N-CHANNEL Power MOSFET
ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Off characteristics						
Drain-Source breakdown voltage	V _{(BR)DS}	60			V	V _{GS} =0V, I _D =250μA
Zero gate voltage drain current	I _{DSS}			1	uA	V _{DS} =60V, V _{GS} =0V
Gate-body leakage current	I _{GSS}			±100	nA	V _{DS} =0V, V _{GS} =±20V
On characteristics (note1)						
Gate-threshold voltage	V _{GS(th)}	2.0	2.8	4	V	V _{DS} =V _{GS} , I _D =250μA
Drain-source on-resistance	R _{DS(ON)}		6.5	8	mΩ	V _{GS} =10V, I _D =20A
			9	12		V _{GS} =4.5V, I _D =20A
Forward transconductance	g _{FS}		15		S	V _{DS} =15V, I _D =24A
Dynamic characteristics (Guaranteed by design, not subject to production)						
Input capacitance	C _{iss}		2000		pF	V _{GS} =0V V _{DS} =25V f=1.0MHz
Output capacitance	C _{oss}		217		pF	
Reverse transfer capacitance	C _{rss}		193		pF	
Switching characteristics (Guaranteed by design, not subject to production)						
Turn-on delay time	t _{d(on)}		13		ns	V _{DD} =25V I _D =20A R _G =1.8 Ω V _{GS} =10V
Turn-on rise time	t _r		7.8		ns	
Turn-off delay time	t _{d(off)}		35		ns	
Turn-off fall time	t _f		15		ns	
Total gate charge	Q _g		30		nC	V _{DD} =25V, V _{GS} =10V , I _D =20A
Gate-source charge	Q _{gs}		9		nC	
Gate-drain charge	Q _{gd}		15		nC	
Drain-source diode characteristics						
Diode forward voltage	V _{SD}			1.2	V	I _S =20A, V _{GS} =0V
Max. forward current	I _S			80	A	
Pulsed drain-source diode forward current	I _{SM}			240	A	

Notes: 1. Pulse Test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.

N-CHANNEL Power MOSFET

TYPICAL CHARACTERISTICS

Fig.1 Power Dissipation

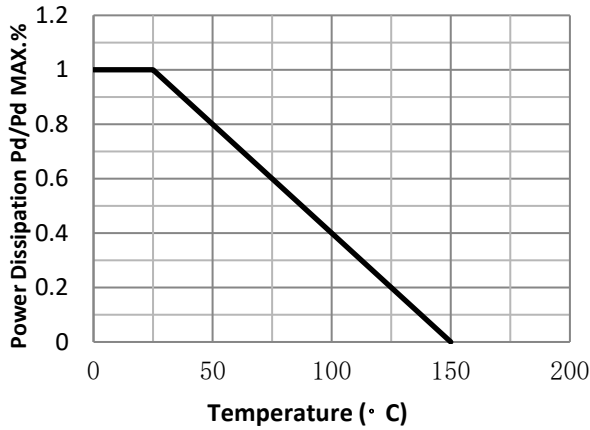


Fig.2 Typical output Characteristics

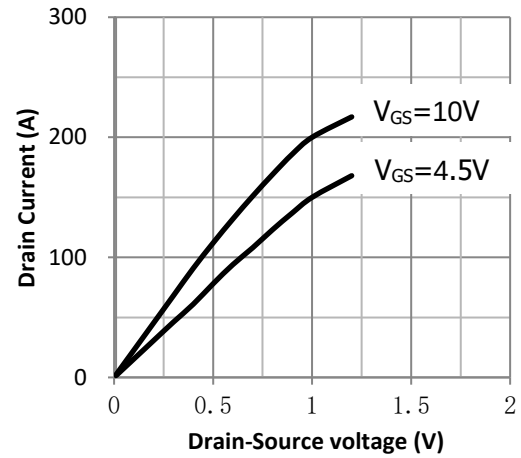


Fig.3 Threshold Voltage V.S Junction Temperature

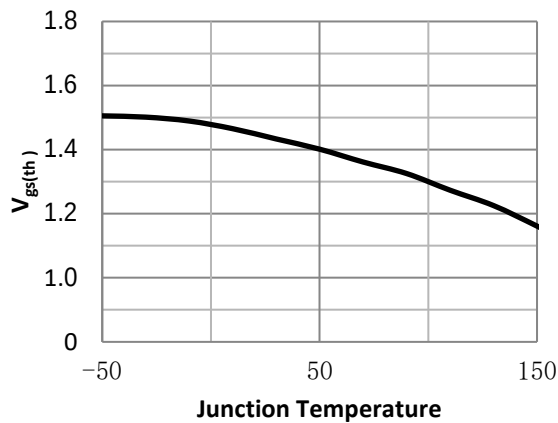


Fig.4 Resistance V.S Drain Current

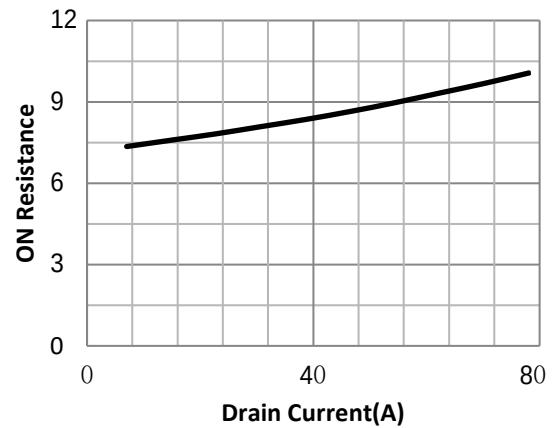


Fig.5 On-Resistance VS Drain Current

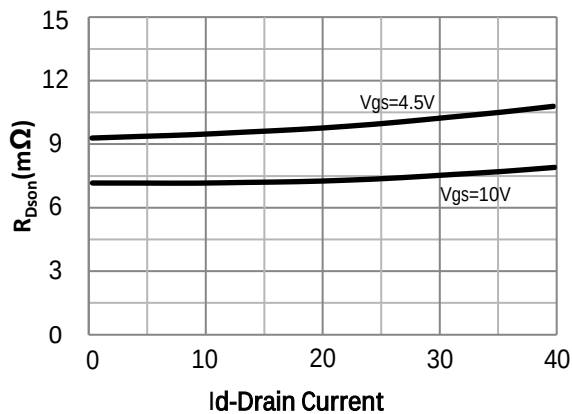
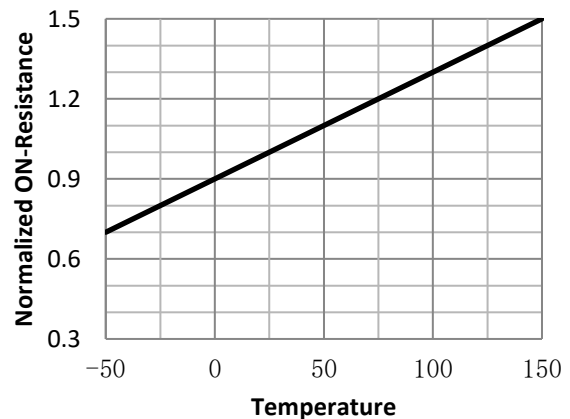
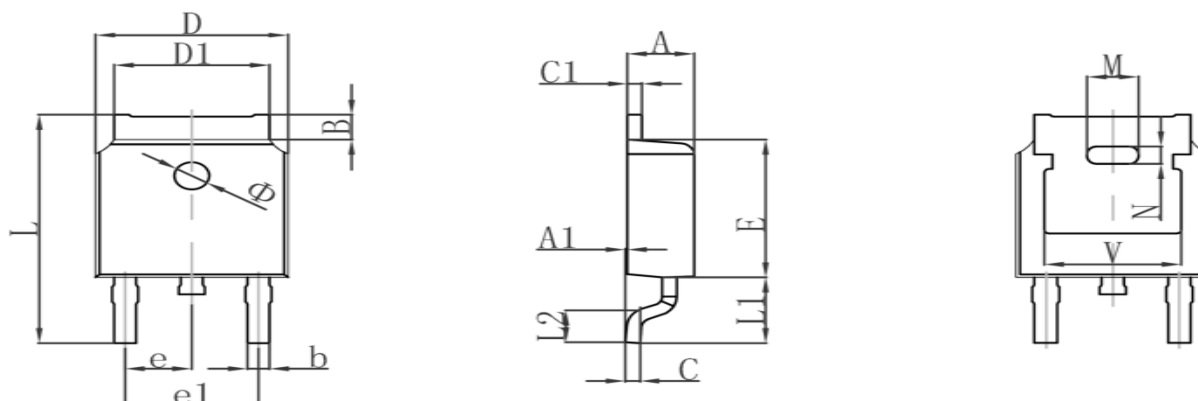
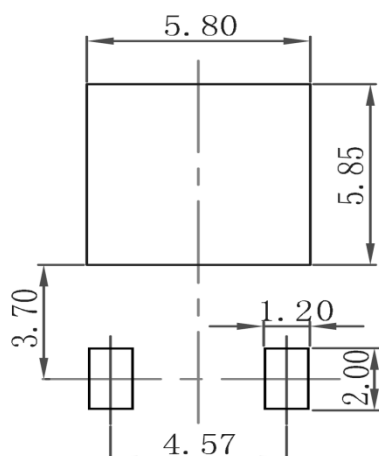


Fig.6 On-Resistance V.S Junction Temperature



N-CHANNEL Power MOSFET
TO-252 PACKAGE OUTLINE DIMENSIONS


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
B	0.800	1.400	0.031	0.055
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
c1	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
E	6.000	6.200	0.236	0.244
e	2.286TYP		0.090TYP	
e1	4.327	4.727	0.170	0.186
M	1.778REF		0.070REF	
N	0.762REF		0.018REF	
L	9.800	10.400	0.386	0.409
L1	2.9REF		0.114REF	
L2	1.400	1.700	0.055	0.067
V	4.830REF		0.190REF	
Φ	1.100	1.300	0.043	0.051

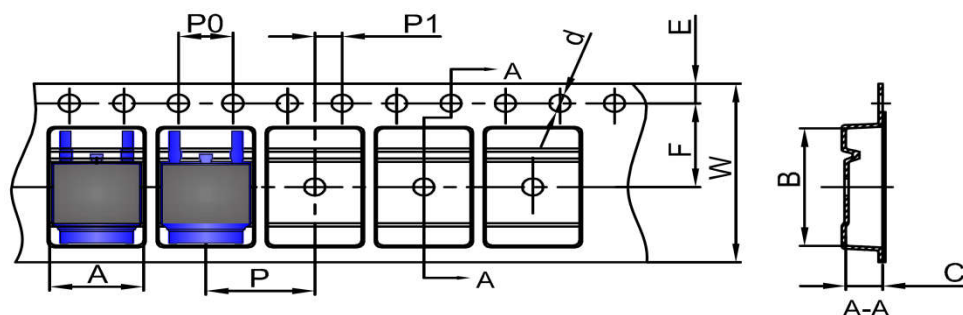
TO-252 SUGGESTED PAD LAYOUT

Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

N-CHANNEL Power MOSFET

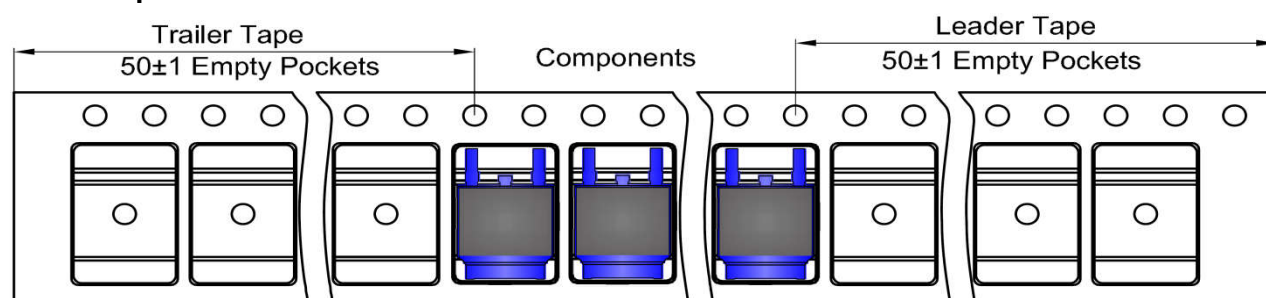
TO-252 TAPE AND REEL

TO-252 Embossed Carrier Tape

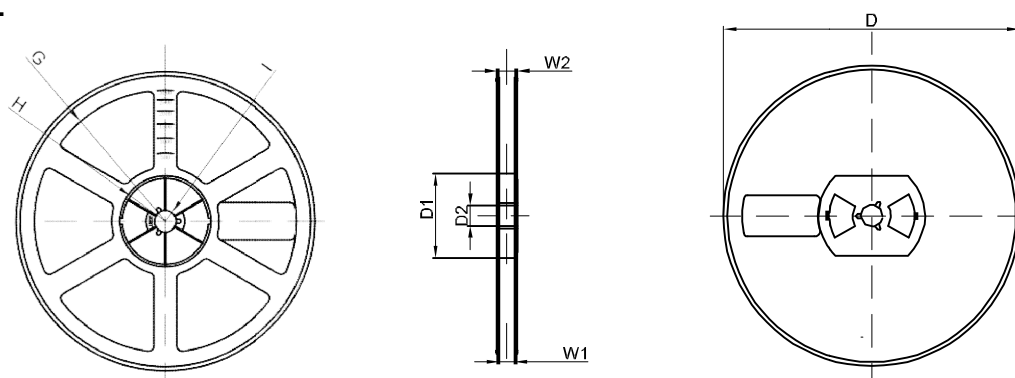


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
TO-252	6.90	10.50	2.70	Ø1.55	1.75	7.50	4.00	8.00	2.00	16.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

TO-252 Tape Leader and Trailer



TO-252 REEL



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
13" DIA	Ø330.00	100.00	Φ21.00	R151.00	R56.00	R6.50	16.40	21.00
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1